SEMICONDUCTOR

74LCX16646 Low Voltage 16-Bit Transceiver/Register with 5V Tolerant Inputs and Outputs

General Description

The LCX16646 contains sixteen non-inverting bidirectional registered bus transceivers with 3-STATE outputs, providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full 16-bit operation. The DIR inputs determine the direction of data flow through the device. The CPAB and CPBA inputs load data into the registers on the LOW-to-HIGH transition (see Functional Description).

The LCX16646 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16646 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- \blacksquare 5.2 ns t_{PD} max (V_{CC} = 3.3V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs

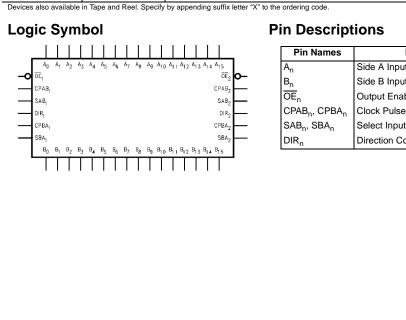
February 1994

Revised August 2002

- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance: Human Body Model > 2000V Machine Model > 200V
- Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX16646MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16646MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide



Pin Names	Description
A _n	Side A Inputs or 3-STATE Outputs
B _n	Side B Inputs or 3-STATE Outputs
OEn	Output Enable Inputs
CPAB _n , CPBA _n	Clock Pulse Inputs
SAB _n , SBA _n	Select Inputs
DIR _n	Direction Control Inputs

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74LCX16646	Connection Diagram		
9			¬
Y	DIF	4 - 1	56 - 0E
ΰ	CPA	B ₁ — 2	55 — CPBA1
Ľ	SAE	B ₁ — 3	54 - SBA
4	GN	ID — 4	53 — GND
7	,	4 ₀ — 5	52 - B ₀
	,	4 ₁ — 6	51 - B
	v		50 - V _{CC}
			49 B2
	4	4 ₃ — 9	48 - B ₃
	1	A ₄ - 10	47 - B ₄
	GN	D - 11	46 GND
	,	A ₅ — 12	45 - B ₅
		A ₆ — 13	44 - B ₆
		A ₇ — 14	43 - B ₇
		A ₈ - 15	42 - B ₈
		A ₉ — 16	4 1 - Bg
	Δ.	17	40 - B ₁₀
	GN	D — 18	39 — GND
	Α.	19	38 B ₁₁
	A	2 - 20	37 - B ₁₂
			36 B ₁₃
			35 - V _{CC}
			34 - B ₁₄
			33 - B ₁₅
			32 — GND
	SAE	B ₂ — 26	31 - SBA2
	CPAE	B ₂ - 27	30 - CPBA ₂
	DIF	R ₂ - 28	29 - OE ₂
		- I	

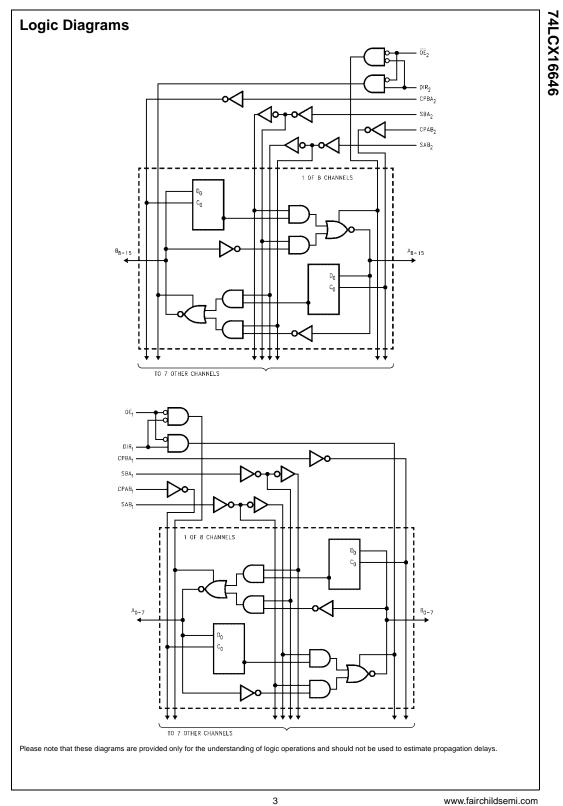
Truth Table

(Note 2)

Inputs					Data I/O		Output Operation Made		
OE ₁	DIR ₁	CPAB ₁	CPBA ₁	SAB ₁	SBA ₁	A ₀₋₇	B ₀₋₇	Output Operation Mode	
Н	Х	H or L	H or L	Х	Х			Isolation	
н	Х	~	Х	Х	Х	Input Input		Clock An Data into A Register	
Н	х	Х	~	х	х		Clock B _n Data Into B Register		
L	Н	Х	Х	L	Х			An to Bn — Real Time (Transparent Mode)	
L	н	~	Х	L	Х	Input	Output	Clock An Data to A Register	
L	н	H or L	Х	н	Х			A Register to B _n (Stored Mode)	
L	н	~	Х	н	х			Clock A_{n} Data into A Register and Output to B_{n}	
L	L	Х	Х	Х	L			B _n to A _n — Real Time (Transparent Mode)	
L	L	Х	~	Х	L	Output	Input	Clock Bn Data into B Register	
L	L	Х	H or L	х	н			B Register to An (Stored Mode)	
L	L	Х	~	Х	Н			Clock ${\rm B_n}$ into B Register and Output to ${\rm A_n}$	

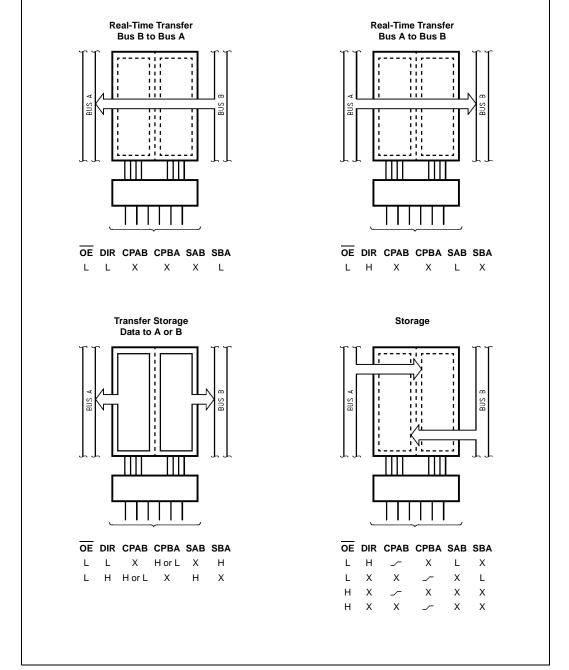
H = HIGH Voltage Level X = Immaterial L = LOW Voltage Level → = LOW-to-HIGH Transition.

Note 2: The data output functions may be enabled or disabled by various signals at the $\overline{\text{OE}}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.



Functional Description

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both. The select (SAB_n, SBA_n) controls can multiplex stored and real-time. The examples shown below demonstrate the four fundamental bus-management functions that can be performed. The direction control (DIR_n) determines which bus will receive data when \overline{OE}_n is LOW. In the isolation mode (\overline{OE}_n HIGH), A data may be stored in one register and/or B data may be stored in the other register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two busses, A or B, may be driven at a time.



Symbol	Parameter	Value	Conditions	Units
√ _{cc}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 4)	v
ік	DC Input Diode Current	-50	V _I < GND	mA
ОК	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	mA
0	DC Output Source/Sink Current	±50		mA
сс	DC Supply Current per Supply Pin	±100		mA
GND	DC Ground Current per Ground Pin	±100		mA
Г _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Min	Max	Units	
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$		±12	mA
		$V_{CC}=2.3V-2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Unused inputs and I/Os must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
-		Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		I _{OH} = -24 mA	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 8 mA	2.3		0.6	
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
I _I	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ
l _{oz}	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$	2.3 - 3.0		±3.0	μΑ
IOFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0	1	10	μA

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DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{cc}	T _A = -40°	C to +85°C	Units
Gymbol	i arameter	Conditions		Min	Max	Onits
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μA
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 6)	2.3 - 3.6		±20	μι
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

		$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500\Omega$						
Symbol	Parameter	V _{CC} = 3.	$3V \pm 0.3V$	V _{CC} :	= 2.7V	V _{CC} = 2.	$5V \pm 0.2V$	Units
	Parameter	C _L =	C _L = 50 pF		C _L = 30 pF		Units	
		Min	Max	Min	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency	170						ns
t _{PHL}	Propagation Delay	1.5	5.2	1.5	6.0	1.5	6.2	
t _{PLH}	Bus to Bus	1.5	5.2	1.5	6.0	1.5	6.2	ns
t _{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns
t _{PLH}	Clock to Bus	1.5	6.0	1.5	7.0	1.5	7.2	ns
t _{PHL}	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	
t _{PLH}	Select to Bus	1.5	6.0	1.5	7.0	1.5	7.2	ns
t _{PZL}	Output Enable Time	1.5	7.5	1.5	8.5	1.5	9.8	
t _{PZH}		1.5	7.5	1.5	8.5	1.5	9.8	ns
t _{PLZ}	Output Disable Time	1.5	6.5	1.5	7.5	1.5	7.8	
t _{PHZ}		1.5	6.5	1.5	7.5	1.5	7.8	ns
t _S	Setup Time	2.5		2.5		3.0		ns
t _H	Hold Time	1.5		1.5		2.0		ns
t _W	Pulse Width	3.0		3.0		3.5		ns
t _{OSHL}	Output to Output Skew (Note 7)		1.0					
tOSLH			1.0					ns

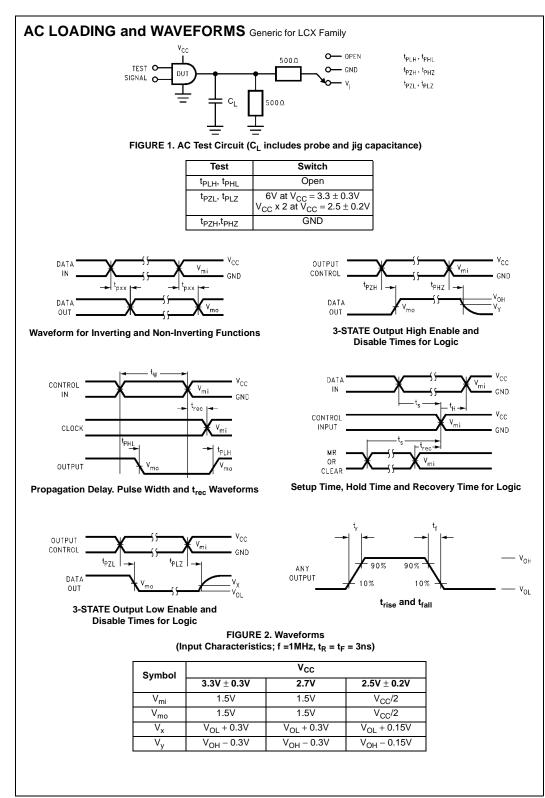
Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
Cymbol	i di diffettori	Contantions	(V)	Typical	onno
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_{L} = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

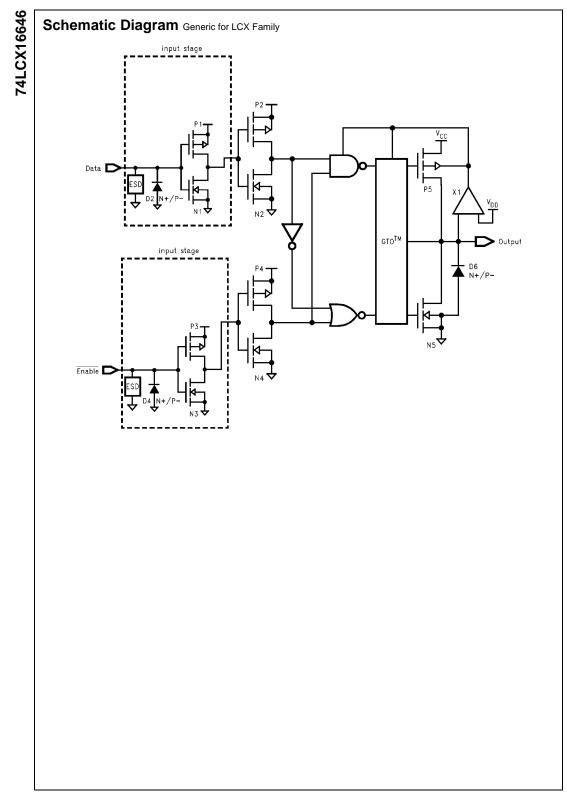
Capacitance

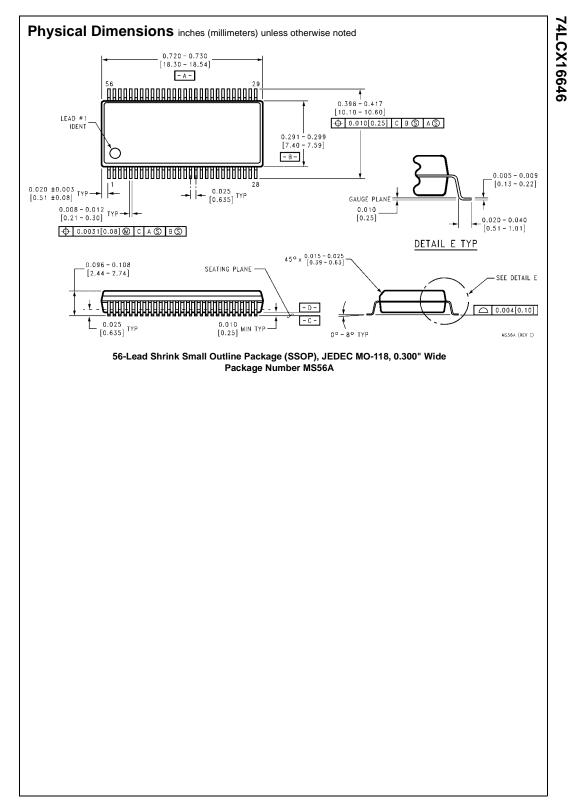
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_{I} = 0V or V_{CC},F = 10 MHz	20	pF



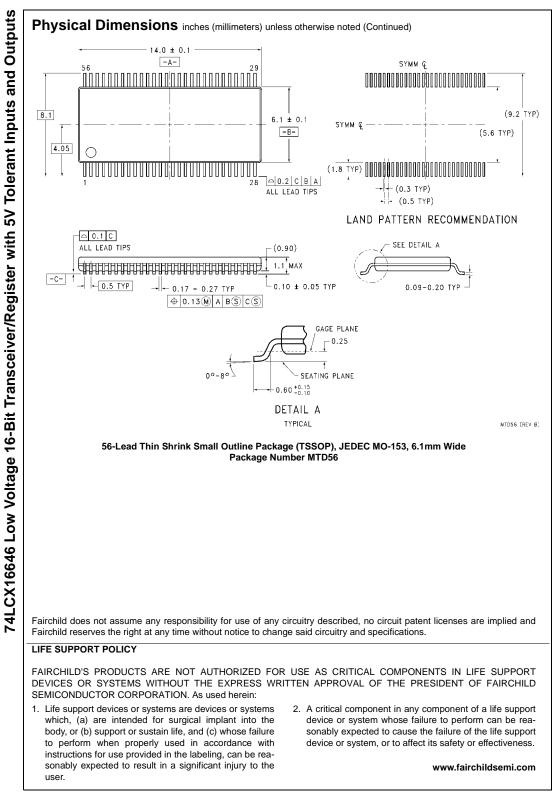
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